

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

[IXYS Corporation](#)
[VUO98-16NO7](#)

For any questions, you can email us directly:
sales@integrated-circuit.com

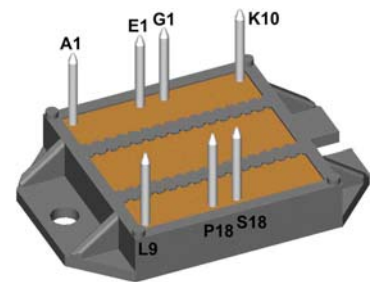
Standard Rectifier Module


3~ Rectifier	
V_{RRM}	= 1600 V
I_{DAV}	= 105 A
I_{FSM}	= 750 A

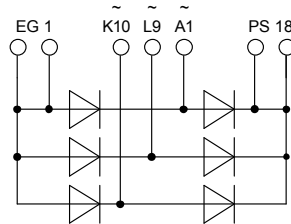
3~ Rectifier Bridge

Part number

VUO98-16NO7



 E72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

- Diode for main rectification
- For three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: ECO-PAC2

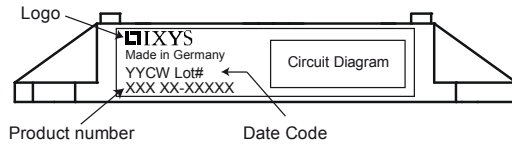
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Height: 9 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Rectifier				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
V_{RSM}	max. non-repetitive reverse blocking voltage				1700	V	
V_{RRM}	max. repetitive reverse blocking voltage				1600	V	
I_R	reverse current	$V_R = 1600$ V			100	μ A	
		$V_R = 1600$ V			1.5	mA	
V_F	forward voltage drop	$I_F = 40$ A			1.14	V	
		$I_F = 120$ A			1.48	V	
		$I_F = 40$ A	$T_{VJ} = 125^\circ$ C			1.06	V
		$I_F = 120$ A				1.51	V
I_{DAV}	bridge output current	$T_C = 115^\circ$ C rectangular $d = 1/3$			105	A	
V_{F0}	threshold voltage	} for power loss calculation only			0.81	V	
r_F	slope resistance				5.9	m Ω	
R_{thJC}	thermal resistance junction to case				0.7	K/W	
R_{thCH}	thermal resistance case to heatsink			0.3		K/W	
P_{tot}	total power dissipation				175	W	
I_{FSM}	max. forward surge current	$t = 10$ ms; (50 Hz), sine	$T_{VJ} = 45^\circ$ C		750	A	
		$t = 8,3$ ms; (60 Hz), sine	$V_R = 0$ V		810	A	
		$t = 10$ ms; (50 Hz), sine	$T_{VJ} = 150^\circ$ C		640	A	
		$t = 8,3$ ms; (60 Hz), sine	$V_R = 0$ V		690	A	
I^2t	value for fusing	$t = 10$ ms; (50 Hz), sine	$T_{VJ} = 45^\circ$ C		2.82	kA ² s	
		$t = 8,3$ ms; (60 Hz), sine	$V_R = 0$ V		2.73	kA ² s	
		$t = 10$ ms; (50 Hz), sine	$T_{VJ} = 150^\circ$ C		2.05	kA ² s	
		$t = 8,3$ ms; (60 Hz), sine	$V_R = 0$ V		1.98	kA ² s	
C_J	junction capacitance	$V_R = 400$ V; $f = 1$ MHz			11	pF	



VUO98-16NO7

Package ECO-PAC2				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal				100	A
T_{stg}	storage temperature			-40		125	°C
T_{vj}	virtual junction temperature			-40		150	°C
Weight					24		g
M_D	mounting torque			1.5		2	Nm
$d_{Spp/App}$	creepage distance on surface striking distance through air	terminal to terminal		6.0			mm
$d_{Spb/Apb}$		terminal to backside		10.0			mm
V_{ISOL}	isolation voltage	t = 1 second	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	3000			V
		t = 1 minute		2500			V

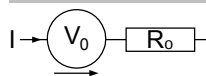


Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	VUO98-16NO7	VUO98-16NO7	Box	25	494526

Equivalent Circuits for Simulation

* on die level

$T_{vj} = 150^\circ\text{C}$



Rectifier

$V_{0\ max}$	threshold voltage	0.81	V
$R_{0\ max}$	slope resistance *	4.6	mΩ

Rectifier

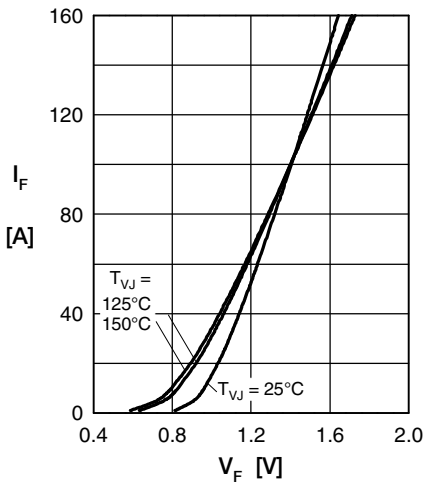


Fig. 1 Forward current versus voltage drop per diode

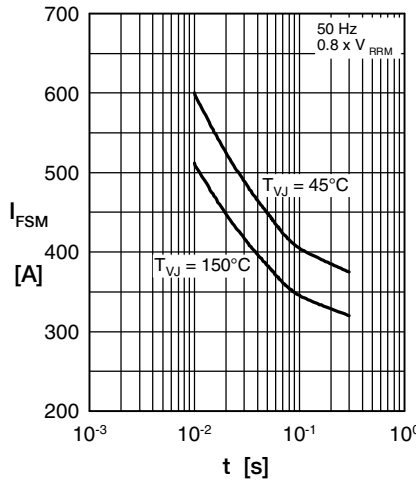


Fig. 2 Surge overload current

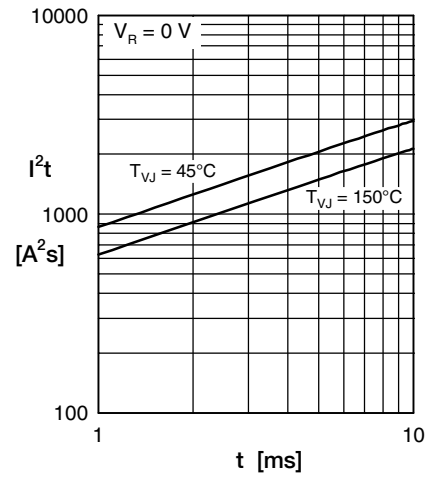


Fig. 3 I²t versus time per diode

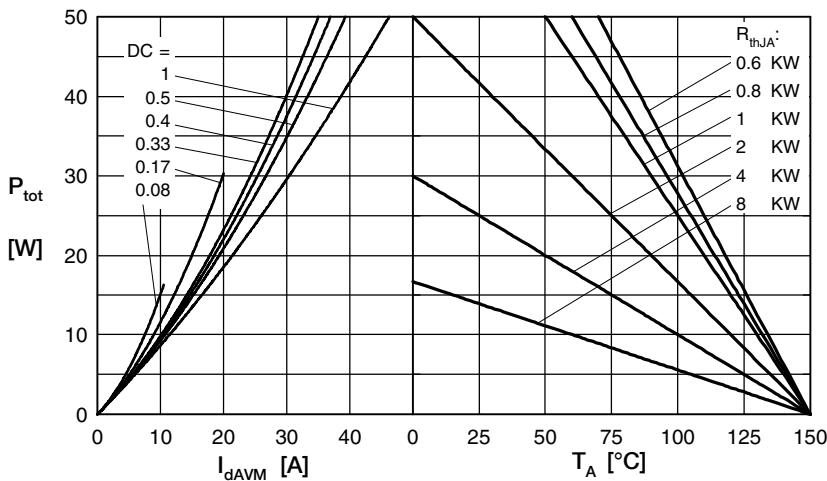


Fig. 4 Power dissipation vs. direct output current & ambient temperature

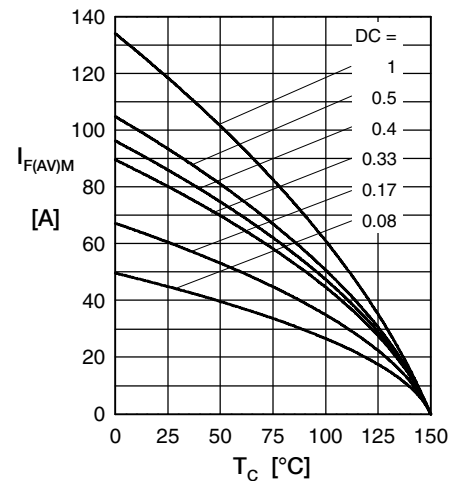


Fig. 5 Max. forward current vs. case temperature

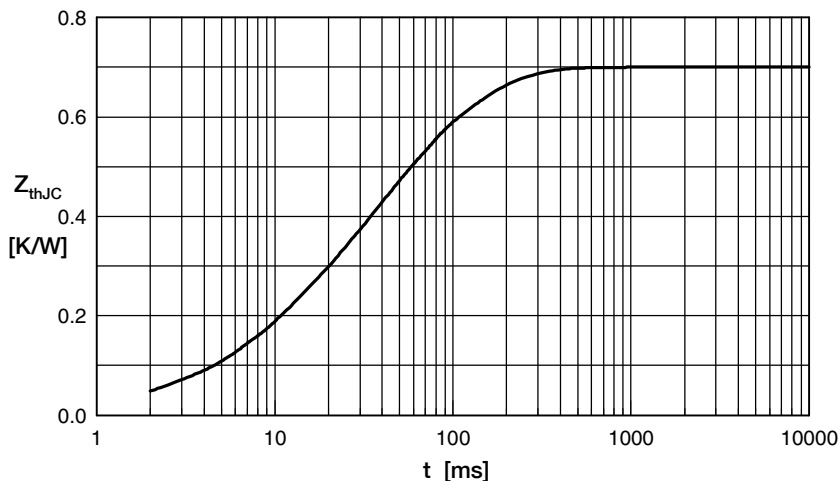


Fig. 6 Transient thermal impedance junction to case

Constants for Z_{thJC} calculation:

i	R _{th} (K/W)	t _i (s)
1	0.09	0.012
2	0.05	0.007
3	0.32	0.036
4	0.24	0.102